Self-Assembled Heterostructure Formation and Direct Exchange Interactions in Epitaxial Nanoislands

Anjan Bhukta, D. Horvitz, Amit Kohn, Ilan Goldfarb,

Department of Materials Science and Engineering, Faculty of Engineering
Tel Aviv University, Ramat Aviv 6997801, Israel
E-mail: ilang@eng.tau.ac.il
URL: http://www.eng.tau.ac.il/~ilang

Yongmei Jin, Ranjit Pati

Department of Materials, and School of Physics, Michigan Technological University, USA

Abstract

Bottom-up fabrication of functional nanostructures requires deep understanding of nucleation and growth processes and their effect on the resulting individual and collective physical properties. The former processes are best observed by in-situ scanning tunneling microscopy (STM). For exploring magnetism at the nanoscale, it makes sense to begin with growing nanostructures of ferromagnetic (FM) elements, such as Fe, Ni and Co, on the substrates of choice. However, as for obvious reasons the substrate of choice is silicon, the reaction of FM adatoms with Si leads to formation of superparamagnetic (SPM) arrays of nanometric silicide islands. On the other hand, the affinity of transition metals for Si, lends itself to selective reaction of the metal adatoms at specific surface sites, affecting not only positioning but the nanostructure size and shape, as well. This way we could tackle the problem of SPM limit by inducing collective dipolar interactions between densely packed islands within ordered or disordered arrays. For other applications, such as magnetic memory cells, magnetic stability of each individual island is required (rather than collective). In this talk, I will show how we approached this goal by using binary FM alloys, e.g., $Ni_{20}Fe_{80}$ Permalloy, instead of elemental metals. In particular, phase transformations and layering inside the ternary silicide islands upon anneal, form FM-FM or FM-AFM sandwich structures coupled by direct exchange interactions.

Short Biography

Ilan Goldfarb is a Professor at the Department of Materials Science and Engineering, Tel Aviv University, and the Head of Surface Science & Nanostructures laboratory. After obtaining his doctorate in growth and transmission electron microscopy of thin films at Technion's Department of Materials in 1994, he spent the next five years at Oxford University's Department of Materials, specializing in surface science, epitaxial growth, and scanning tunneling microscopy. He joined Tel Aviv University in 1999, and spent his 2010-2011 sabbatical year at Hewlett-Packard Laboratories in Palo Alto. Throughout the years, Prof. Goldfarb has headed the TAU Wolfson Applied Materials Research Centre, the Department of Materials Science and Engineering, and served on the Editorial Board of Applied Physics A. His current research focuses on growth of thin films and nanostructures, nanoscale magnetic properties of self-organized epitaxial deposits using scanning probes, and on electronic structure and conduction mechanisms of amorphous oxide films.